

OKI Semiconductor**FEDD51V65165E-02**
Issue Date: Aug. 28, 2002**MD51V65165E****4,194,304-Word × 16-Bit DYNAMIC RAM : FAST PAGE MODE TYPE WITH EDO****DESCRIPTION**

The MD51V65165E is a 4,194,304-word × 16-bit dynamic RAM fabricated in Oki's silicon-gate CMOS technology. The MD51V65165E achieves high integration, high-speed operation, and low-power consumption because Oki manufactures the device in a quadruple-layer polysilicon/double-layer metal CMOS process. The MD51V65165E is available in a 50-pin plastic TSOP.

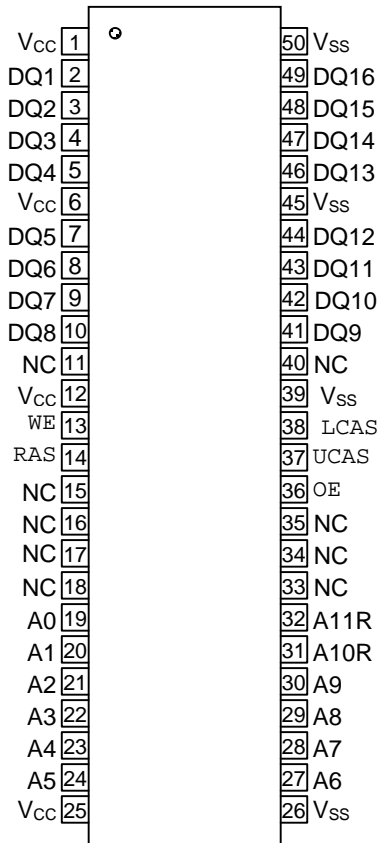
FEATURES

- 4,194,304-word × 16-bit configuration
- Single 3.3V power supply, ±0.3V tolerance
- Input : LVTTL compatible, low input capacitance
- Output : LVTTL compatible, 3-state
- Refresh :
 - RAS only refresh : 4096 cycles/64ms
 - CAS before RAS refresh, hidden refresh : 4096 cycles/64ms
- Fast page mode with EDO, read modify write capability
- CAS before RAS refresh, hidden refresh, RAS-only refresh capability
- Packages
 - 50-pin 400mil plastic TSOP (TSOPII50-P-400-0.80-K) (Product : MD51V65165E-xxTA)
xx indicates speed rank.

PRODUCT FAMILY

| Family | Access Time (Max.) | | | | Cycle Time (Min.) | Power Dissipation | |
|-------------|--------------------|-----------------|------------------|------------------|----------------------|---------------------|-------------------|
| | t _{RAC} | t _{AA} | t _{CAC} | t _{OEA} | | Operating (Max.) | Standby (Max.) |
| MD51V65165E | 50ns | 25ns | 13ns | 13ns | 84ns | 504mW | 1.8mW |
| | 60ns | 30ns | 15ns | 15ns | 104ns | 432mW | |

PIN CONFIGURATION (TOP VIEW)

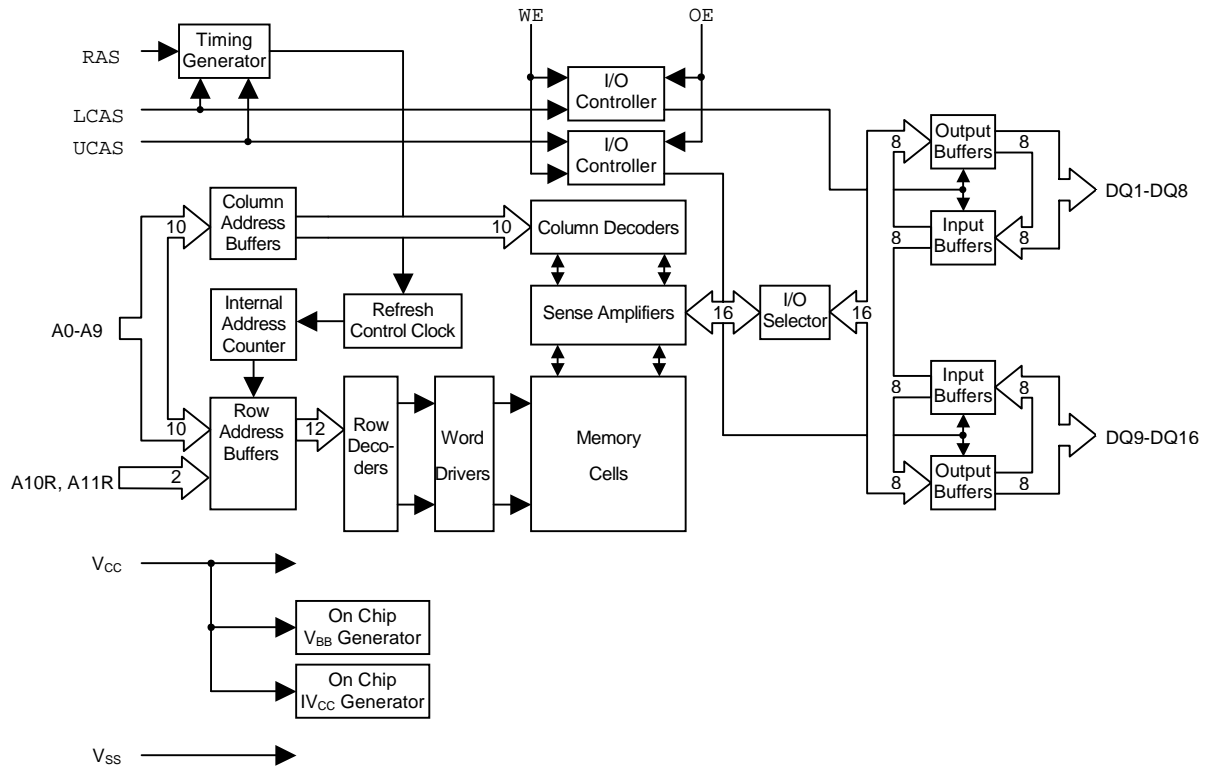


50-Pin Plastic TSOP
(K Type)

| Pin Name | Function |
|-------------------|----------------------------------|
| A0–A9, A10R, A11R | Address Input |
| RAS | Row Address Strobe |
| LCAS | Lower Byte Column Address Strobe |
| UCAS | Upper Byte Column Address Strobe |
| DQ1–DQ16 | Data Input/Data Output |
| OE | Output Enable |
| WE | Write Enable |
| V _{CC} | Power Supply (3.3V) |
| V _{SS} | Ground (0V) |
| NC | No Connection |

Note : The same power supply voltage must be provided to every V_{CC} pin, and the same GND voltage level must be provided to every V_{SS} pin.

BLOCK DIAGRAM



FUNCTION TABLE

| Input Pin | | | | | DQ Pin | | Function Mode |
|-----------|------|------|----|----|------------------|------------------|------------------|
| RAS | LCAS | UCAS | WE | OE | DQ1-DQ8 | DQ9-DQ16 | |
| H | * | * | * | * | High-Z | High-Z | Standby |
| L | H | H | * | * | High-Z | High-Z | Refresh |
| L | L | H | H | L | D _{OUT} | High-Z | Lower Byte Read |
| L | H | L | H | L | High-Z | D _{OUT} | Upper Byte Read |
| L | L | L | H | L | D _{OUT} | D _{OUT} | Word Read |
| L | L | H | L | H | D _{IN} | Don't Care | Lower Byte Write |
| L | H | L | L | H | Don't Care | D _{IN} | Upper Byte Write |
| L | L | L | L | H | D _{IN} | D _{IN} | Word Write |
| L | L | L | H | H | High-Z | High-Z | — |

* : "H" or "L"

ELECTRICAL CHARACTERISTICS**ABSOLUTE MAXIMUM RATINGS**

| Parameter | Symbol | Value | Unit |
|--|-------------------|----------------------|------|
| Voltage on Any Pin Relative to V_{SS} | V_{IN}, V_{OUT} | -0.5 to $V_{CC}+0.5$ | V |
| Voltage V_{CC} Supply relative to V_{SS} | V_{CC} | -0.5 to 4.6 | V |
| Short Circuit Output Current | I_{OS} | 50 | mA |
| Power Dissipation | P_{D^*} | 1 | W |
| Operating Temperature | T_{opr} | 0 to 70 | °C |
| Storage Temperature | T_{stg} | -55 to 150 | °C |

*: $T_a = 25^{\circ}\text{C}$ **RECOMMENDED OPERATING CONDITIONS**

(Ta = 0 to 70°C)

| Parameter | Symbol | Min. | Typ. | Max. | Unit |
|----------------------|----------|-------------|------|---------------------|------|
| Power Supply Voltage | V_{CC} | 3.0 | 3.3 | 3.6 | V |
| | V_{SS} | 0 | 0 | 0 | V |
| Input High Voltage | V_{IH} | 2.0 | — | $V_{CC} + 0.3^{*1}$ | V |
| Input Low Voltage | V_{IL} | -0.3^{*2} | — | 0.8 | V |

Notes: *1. The input voltage is $V_{CC} + 1.0\text{V}$ when the pulse width is less than 20ns (the pulse width is with respect to the point at which V_{CC} is applied).

*2. The input voltage is $V_{SS} - 1.0\text{V}$ when the pulse width is less than 20ns (the pulse width respect to the point at which V_{SS} is applied).

PIN CAPACITANCE

(Vcc = 3.3V ± 0.3V, Ta = 25°C, f = 1 MHz)

| Parameter | Symbol | Min. | Max. | Unit |
|--|-----------|------|------|------|
| Input Capacitance (A0 – A9, A10R, A11R) | C_{IN1} | — | 5 | pF |
| Input Capacitance (RAS, LCAS, UCAS, WE, OE) | C_{IN2} | — | 7 | pF |
| Output Capacitance (DQ1 - DQ16) | $C_{I/O}$ | — | 7 | pF |

DC CHARACTERISTICS

(V_{CC} = 3.3V ± 0.3V, Ta = 0 to 70°C)

| Parameter | Symbol | Condition | MD51V65165 E-50 | | MD51V65165 E-60 | | Unit | Note |
|---|------------------|--|--------------------|-----------------|--------------------|-----------------|------|------|
| | | | Min. | Max. | Min. | Max. | | |
| Output High Voltage | V _{OH} | I _{OH} = -2.0mA | 2.4 | V _{CC} | 2.4 | V _{CC} | V | |
| Output Low Voltage | V _{OL} | I _{OL} = 2mA | 0 | 0.4 | 0 | 0.4 | V | |
| Input Leakage Current | I _{LI} | 0V ≤ V _I ≤ V _{CC} +0.3V; All other pins not under test = 0V | - 10 | 10 | - 10 | 10 | μA | |
| Output Leakage Current | I _{LO} | DQ disable 0V ≤ V _O ≤ V _{CC} | - 10 | 10 | - 10 | 10 | μA | |
| Average Power Supply Current (Operating) | I _{CC1} | RAS, CAS cycling, t _{RC} = Min. | — | 140 | — | 120 | mA | 1,2 |
| Power Supply Current (Standby) | I _{CC2} | RAS, CAS = V _{IH} | — | 2 | — | 2 | mA | 1 |
| | | RAS, CAS ≥ V _{CC} - 0.2V | — | 0.5 | — | 0.5 | | |
| Average Power Supply Current (RAS-only Refresh) | I _{CC3} | RAS cycling, CAS = V _{IH} , t _{RC} = Min. | — | 140 | — | 120 | mA | 1,2 |
| Power Supply Current (Standby) | I _{CC5} | RAS = V _{IH} , CAS = V _{IL} , DQ = enable | — | 5 | — | 5 | mA | 1 |
| Average Power Supply Current (CAS before RAS Refresh) | I _{CC6} | RAS = cycling, CAS before RAS | — | 140 | — | 120 | mA | 1,2 |
| Average Power Supply Current (Fast Page Mode) | I _{CC7} | RAS = V _{IL} , CAS cycling, t _{HPC} = Min. | — | 140 | — | 120 | mA | 1,3 |

Notes: 1. I_{CC} Max. is specified as I_{CC} for output open condition.2. The address can be changed once or less while RAS = V_{IL}.3. The address can be changed once or less while CAS = V_{IH}.

AC CHARACTERISTICS (1/2)

(V_{CC} = 3.3V ± 0.3V, Ta = 0 to 70°C) Note1,2,3

| Parameter | Symbol | MD51V65165 E-50 | | MD51V65165 E-60 | | Unit | Note |
|---|--------------------|--------------------|---------|--------------------|---------|------|---------|
| | | Min. | Max. | Min. | Max. | | |
| Random Read or Write Cycle Time | t _{RC} | 84 | — | 104 | — | ns | |
| Read Modify Write Cycle Time | t _{RWC} | 110 | — | 135 | — | ns | |
| Fast Page Mode Cycle Time | t _{HPC} | 20 | — | 25 | — | ns | |
| Fast Page Mode Read Modify Write Cycle Time | t _{HPRWC} | 58 | — | 68 | — | ns | |
| Access Time from RAS | t _{RAC} | — | 50 | — | 60 | ns | 4, 5, 6 |
| Access Time from CAS | t _{CAC} | — | 13 | — | 15 | ns | 4,5 |
| Access Time from Column Address | t _{AA} | — | 25 | — | 30 | ns | 4,6 |
| Access Time from CAS Precharge | t _{CPA} | — | 30 | — | 35 | ns | 4,13 |
| Access Time from OE | t _{OEa} | — | 13 | — | 15 | ns | 4 |
| Output Low Impedance Time from CAS | t _{CLZ} | 0 | — | 0 | — | ns | 4 |
| Data Output Hold After CAS Low | t _{DOH} | 5 | — | 5 | — | ns | |
| CAS to Data Output Buffer Turn-off Delay Time | t _{CEZ} | 0 | 13 | 0 | 15 | ns | 7,8 |
| RAS to Data Output Buffer Turn-off Delay Time | t _{REZ} | 0 | 13 | 0 | 15 | ns | 7,8 |
| OE to Data Output Buffer Turn-off Delay Time | t _{OEZ} | 0 | 13 | 0 | 15 | ns | 7 |
| WE to Data Output Buffer Turn-off Delay Time | t _{WEZ} | 0 | 13 | 0 | 15 | ns | 7 |
| Transition Time | t _T | 1 | 50 | 1 | 50 | ns | 3 |
| Refresh Period | t _{REF} | — | 64 | — | 64 | ms | |
| RAS Precharge Time | t _{RP} | 30 | — | 40 | — | ns | |
| RAS Pulse Width | t _{RAS} | 50 | 10,000 | 60 | 10,000 | ns | |
| RAS Pulse Width (Fast Page Mode with EDO) | t _{RASP} | 50 | 100,000 | 60 | 100,000 | ns | |
| RAS Hold Time | t _{RSH} | 7 | — | 10 | — | ns | |
| RAS Hold Time referenced to OE | t _{ROH} | 7 | — | 10 | — | ns | |
| CAS Precharge Time (Fast Page Mode with EDO) | t _{CP} | 7 | — | 10 | — | ns | 15 |
| CAS Pulse Width | t _{CAS} | 7 | 10,000 | 10 | 10,000 | ns | |
| CAS Hold Time | t _{CSH} | 35 | — | 40 | — | ns | |
| CAS to RAS Precharge Time | t _{CRP} | 5 | — | 5 | — | ns | 13 |
| RAS Hold Time from CAS Precharge | t _{RHCP} | 30 | — | 35 | — | ns | 13 |
| OE Hold Time from CAS (DQ Disable) | t _{CHO} | 5 | — | 5 | — | ns | |

AC CHARACTERISTICS (2/2)

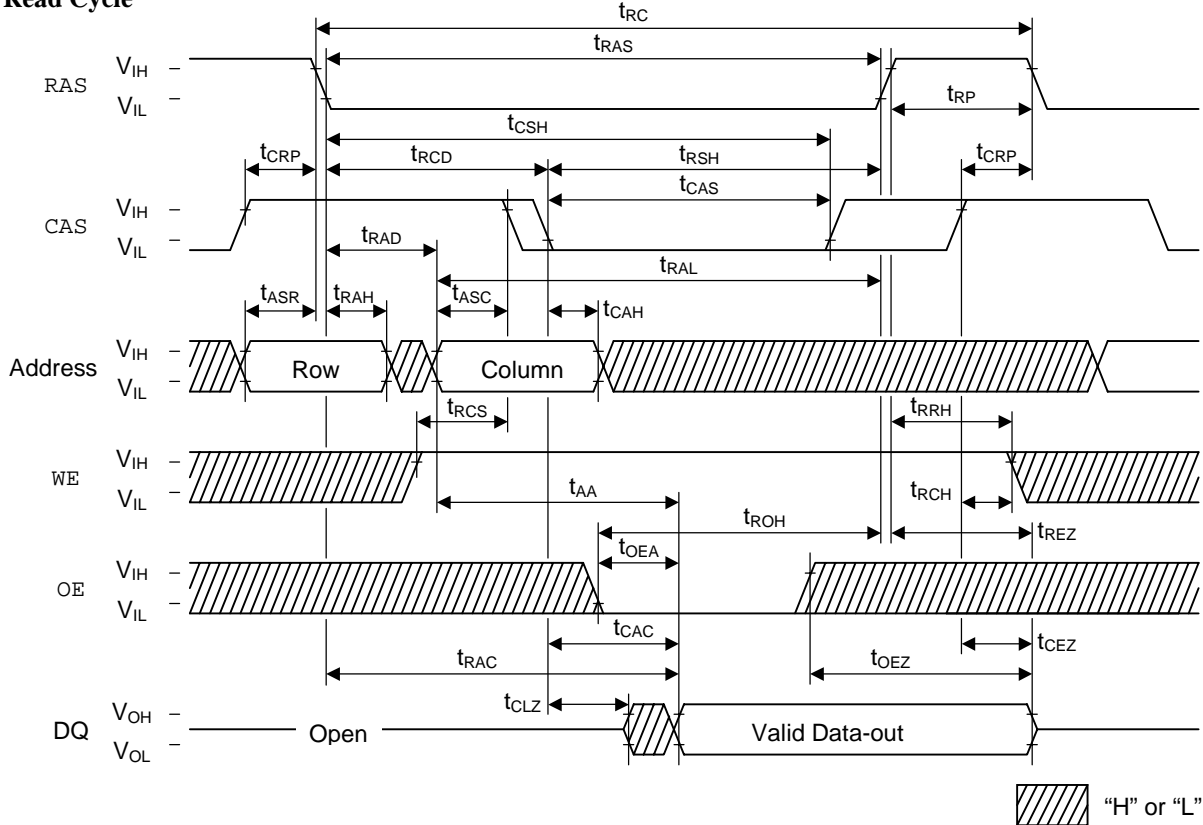
(V_{CC} = 3.3V ± 0.3V, Ta = 0 to 70°C) Note1,2,3

| Parameter | Symbol | MD51V65165 E-50 | | MD51V65165 E-60 | | Unit | Note |
|---|-------------------|--------------------|------|--------------------|------|------|-------|
| | | Min. | Max. | Min. | Max. | | |
| RAS to CAS Delay Time | t _{RCD} | 11 | 37 | 14 | 45 | ns | 5 |
| RAS to Column Address Delay Time | t _{RAD} | 9 | 25 | 12 | 30 | ns | 6 |
| Row Address Set-up Time | t _{ASR} | 0 | — | 0 | — | ns | |
| Row Address Hold Time | t _{RAH} | 7 | — | 10 | — | ns | |
| Column Address Set-up Time | t _{ASC} | 0 | — | 0 | — | ns | 12 |
| Column Address Hold Time | t _{CAH} | 7 | — | 10 | — | ns | 12 |
| Column Address to RAS Lead Time | t _{RAL} | 25 | — | 30 | — | ns | |
| Read Command Set-up Time | t _{RCS} | 0 | — | 0 | — | ns | 12 |
| Read Command Hold Time | t _{RCH} | 0 | — | 0 | — | ns | 9,12 |
| Read Command Hold Time referenced to RAS | t _{RRH} | 0 | — | 0 | — | ns | 9 |
| Write Command Set-up Time | t _{WCS} | 0 | — | 0 | — | ns | 10,12 |
| Write Command Hold Time | t _{WCH} | 7 | — | 10 | — | ns | 12 |
| Write Command Pulse Width | t _{Wp} | 7 | — | 10 | — | ns | |
| WE Pulse Width (DQ Disable) | t _{WPE} | 7 | — | 10 | — | ns | |
| OE Command Hold Time | t _{OEh} | 7 | — | 10 | — | ns | |
| OE Precharge Time | t _{OEP} | 7 | — | 10 | — | ns | |
| OE Command Hold Time | t _{OEh} | 7 | — | 10 | — | ns | |
| Write Command to RAS Lead Time | t _{RWL} | 7 | — | 10 | — | ns | |
| Write Command to CAS Lead Time | t _{CWL} | 7 | — | 10 | — | ns | 14 |
| Data-in Set-up Time | t _{DS} | 0 | — | 0 | — | ns | 11,12 |
| Data-in Hold Time | t _{DH} | 7 | — | 10 | — | ns | 11,12 |
| OE to Data-in Delay Time | t _{OED} | 13 | — | 15 | — | ns | |
| CAS to WE Delay Time | t _{CWD} | 30 | — | 34 | — | ns | 10 |
| Column Address to WE Delay Time | t _{AWD} | 42 | — | 49 | — | ns | 10 |
| RAS to WE Delay Time | t _{RWD} | 67 | — | 79 | — | ns | 10 |
| CAS Precharge WE Delay Time | t _{CPWD} | 47 | — | 54 | — | ns | 10 |
| CAS Active Delay Time from RAS Precharge | t _{RPC} | 5 | — | 5 | — | ns | 12 |
| RAS to CAS Set-up Time (CAS before RAS) | t _{CSR} | 5 | — | 5 | — | ns | 12 |
| RAS to CAS Hold Time(CAS before RAS) | t _{CHR} | 10 | — | 10 | — | ns | 13 |
| WE to RAS Hold Time(CAS before RAS) | t _{WRP} | 10 | — | 10 | — | ns | |
| WE Hold Time(CAS before RAS) | t _{WRH} | 10 | — | 10 | — | ns | |

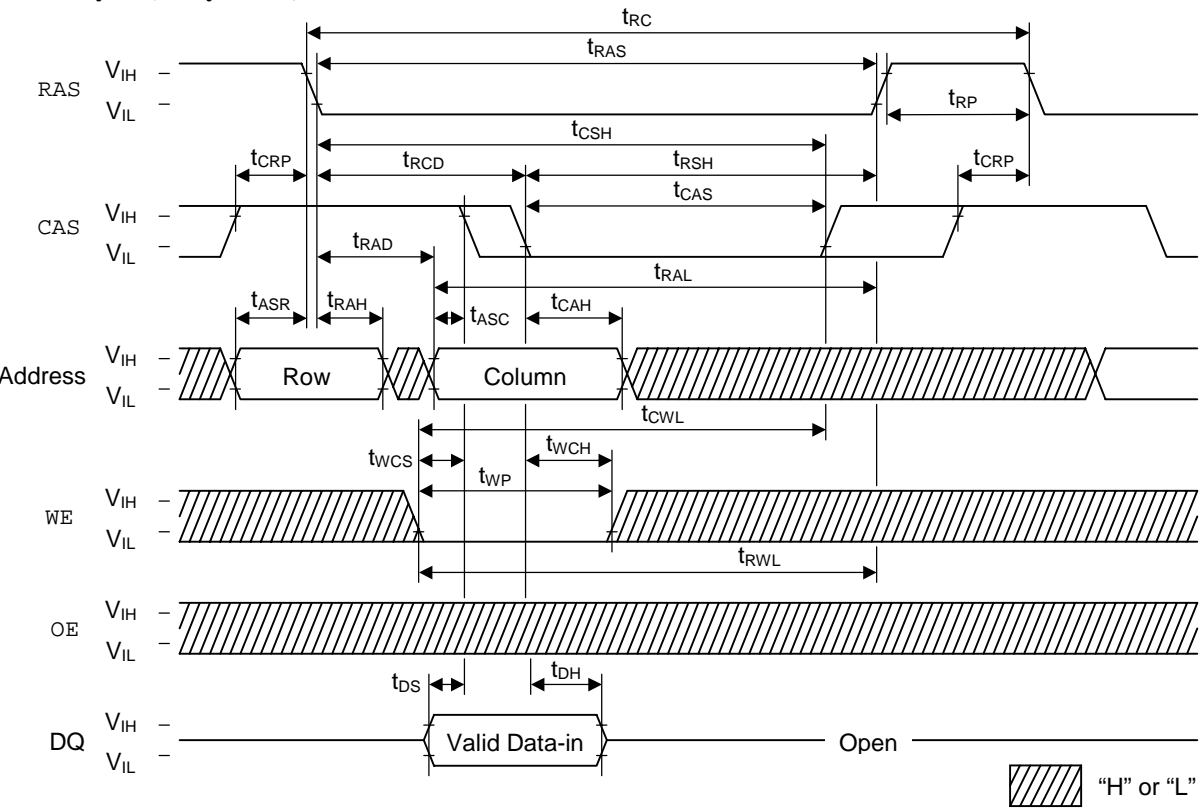
- Notes:
1. A start-up delay of 200 μ s is required after power-up, followed by a minimum of eight initialization cycles (RAS-only refresh or CAS before RAS refresh) before proper device operation is achieved.
 2. The AC characteristics assume $t_T = 2$ ns.
 3. V_{IH} (Min.) and V_{IL} (Max.) are reference levels for measuring input timing signals. Transition times (t_T) are measured between V_{IH} and V_{IL} .
 4. This parameter is measured with a load circuit equivalent to 1 TTL load and 100pF. The output timing reference levels are $V_{OH}=2.0$ and $V_{OL}=0.8$ V.
 5. Operation within the t_{RCD} (Max.) limit ensures that t_{RAC} (Max.) can be met. t_{RCD} (Max.) is specified as a reference point only. If t_{RCD} is greater than the specified t_{RCD} (Max.) limit, then the access time is controlled by t_{CAC} .
 6. Operation within the t_{RAD} (Max.) limit ensures that t_{RAC} (Max.) can be met. t_{RAD} (Max.) is specified as a reference point only. If t_{RAD} is greater than the specified t_{RAD} (Max.) limit, then the access time is controlled by t_{AA} .
 7. t_{CEZ} (Max.), t_{REZ} (Max.), t_{WEZ} (Max.), and t_{OEZ} (Max.) define the time at which the output achieved the open circuit condition and are not referenced to output voltage levels.
 8. t_{CEZ} , and t_{REZ} must be satisfied for open circuit condition.
 9. t_{RCH} or t_{RRH} must be satisfied for a read cycle.
 10. t_{WCS} , t_{CWD} , t_{RWD} , t_{AWD} and t_{CPWD} are not restrictive operating parameters. They are included in the data sheet as electrical characteristics only. If $t_{WCS} \geq t_{WCS}$ (Min.), then the cycle is an early write cycle and the data out will remain open circuit (high impedance) throughout the entire cycle. If $t_{CWD} \geq t_{CWD}$ (Min.), $t_{RWD} \geq t_{RWD}$ (Min.), $t_{AWD} \geq t_{AWD}$ (Min.) and $t_{CPWD} \geq t_{CPWD}$ (Min.), then the cycle is a read modify write cycle and data out will contain data read from the selected cell; if neither of the above sets of conditions is satisfied, then the condition of the data out (at access time) is indeterminate.
 11. These parameters are referenced to the UCAS and LCAS, leading edges in an early write cycle, and to the WE leading edge in an OE control write cycle, or a read modify write cycle.
 12. These parameters are determined by the falling edge of either UCAS or LCAS, whichever is earlier.
 13. These parameters are determined by the rising edge of either UCAS or LCAS, whichever is later.
 14. t_{CWL} should be satisfied by both UCAS and LCAS.
 15. t_{CP} is determined by the time both UCAS and LCAS are high.

TIMING CHART

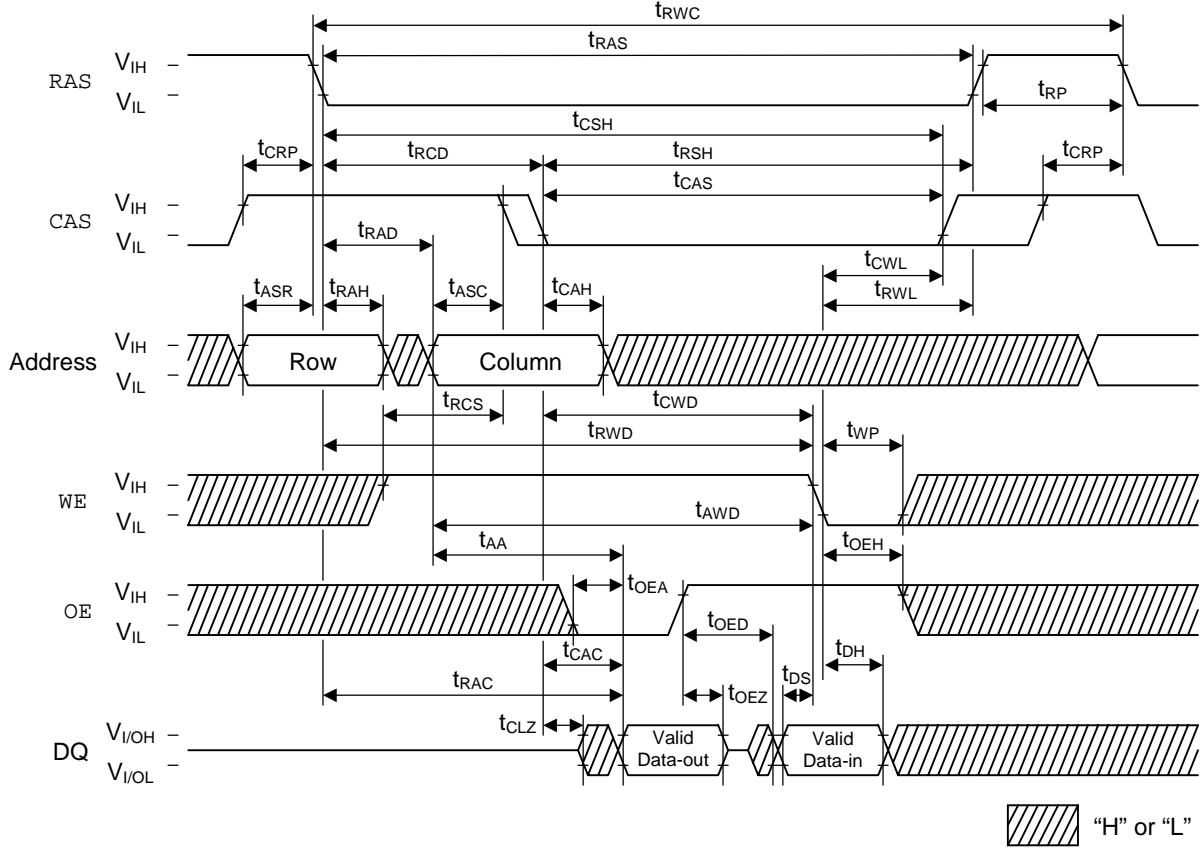
Read Cycle



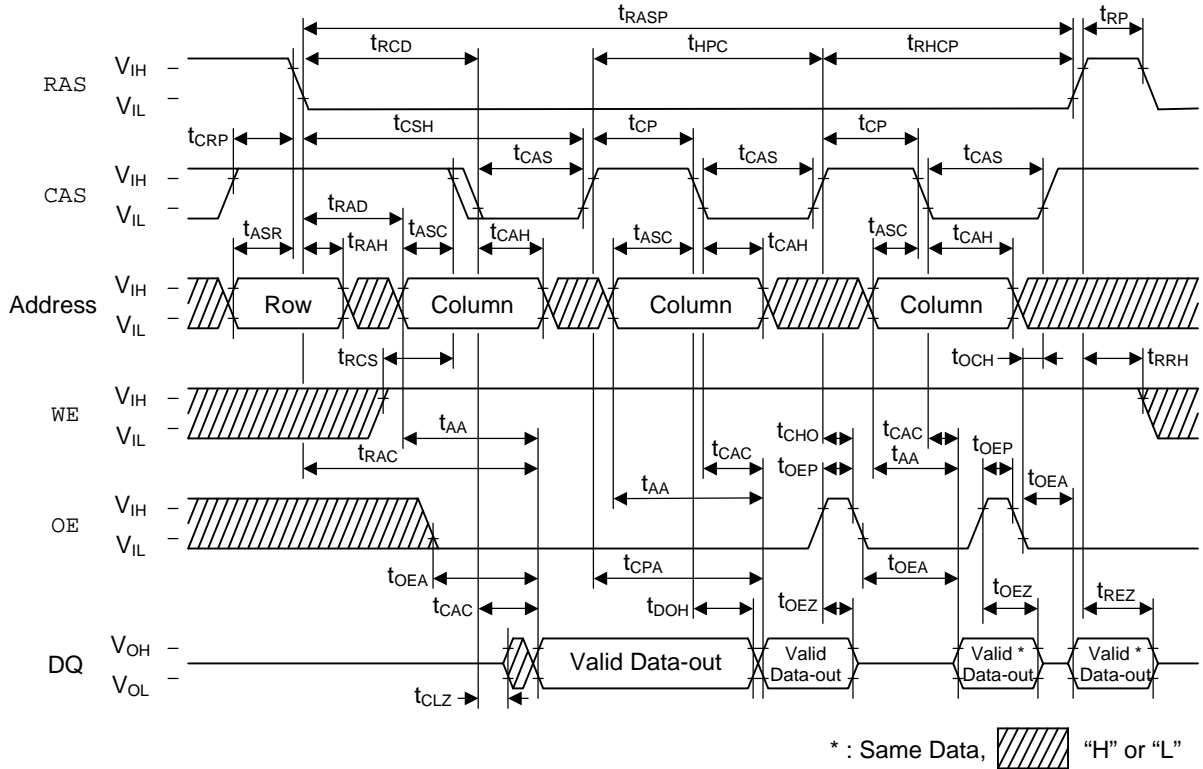
Write Cycle (Early Write)



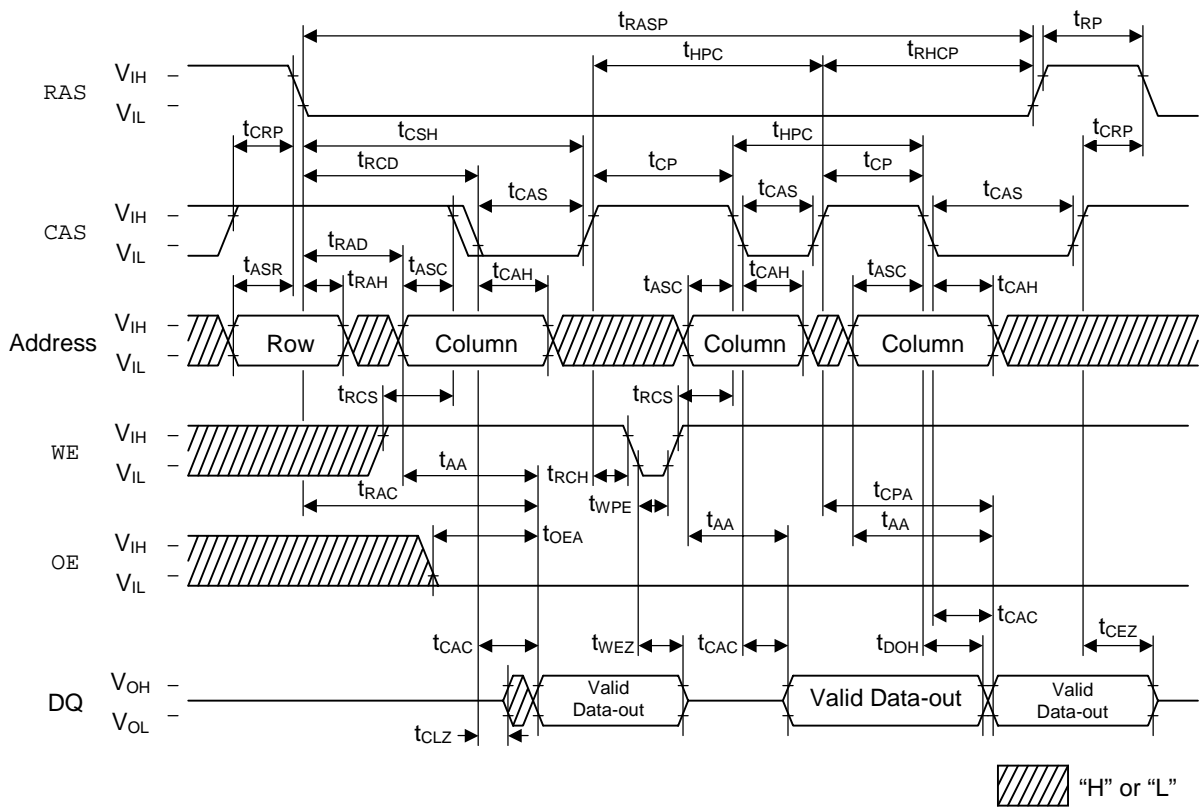
Read Modify Write Cycle



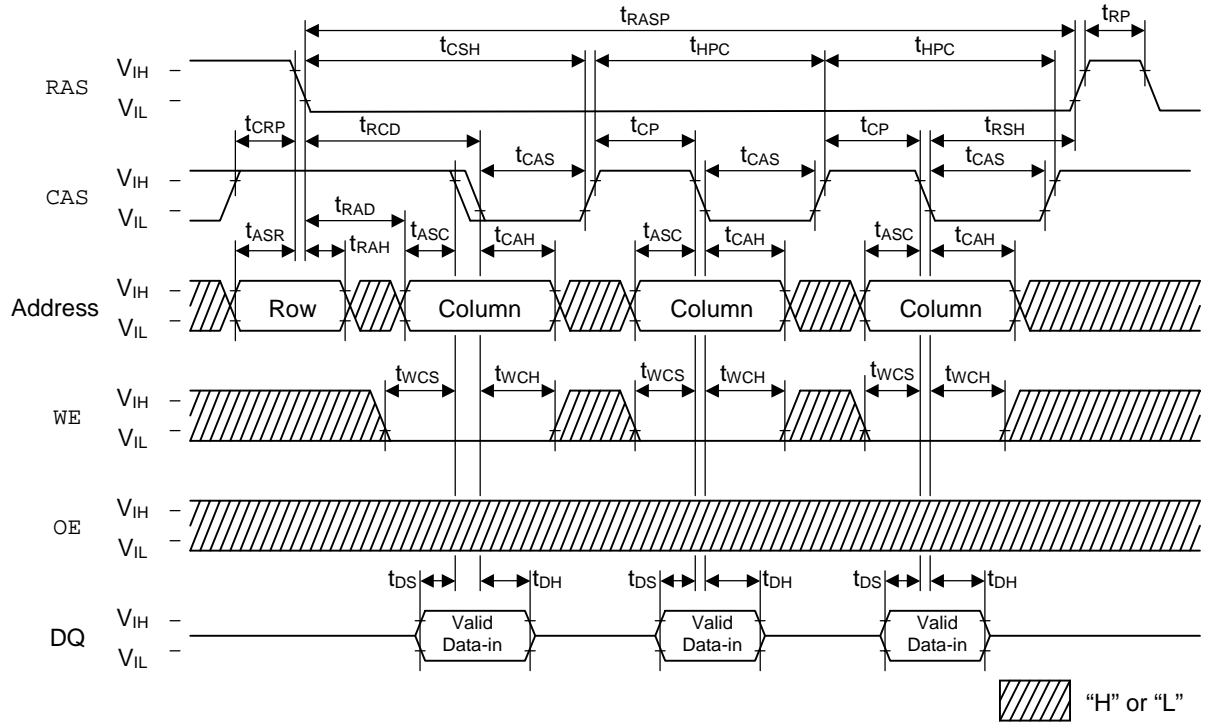
Fast Page Mode Read Cycle (Part-1)



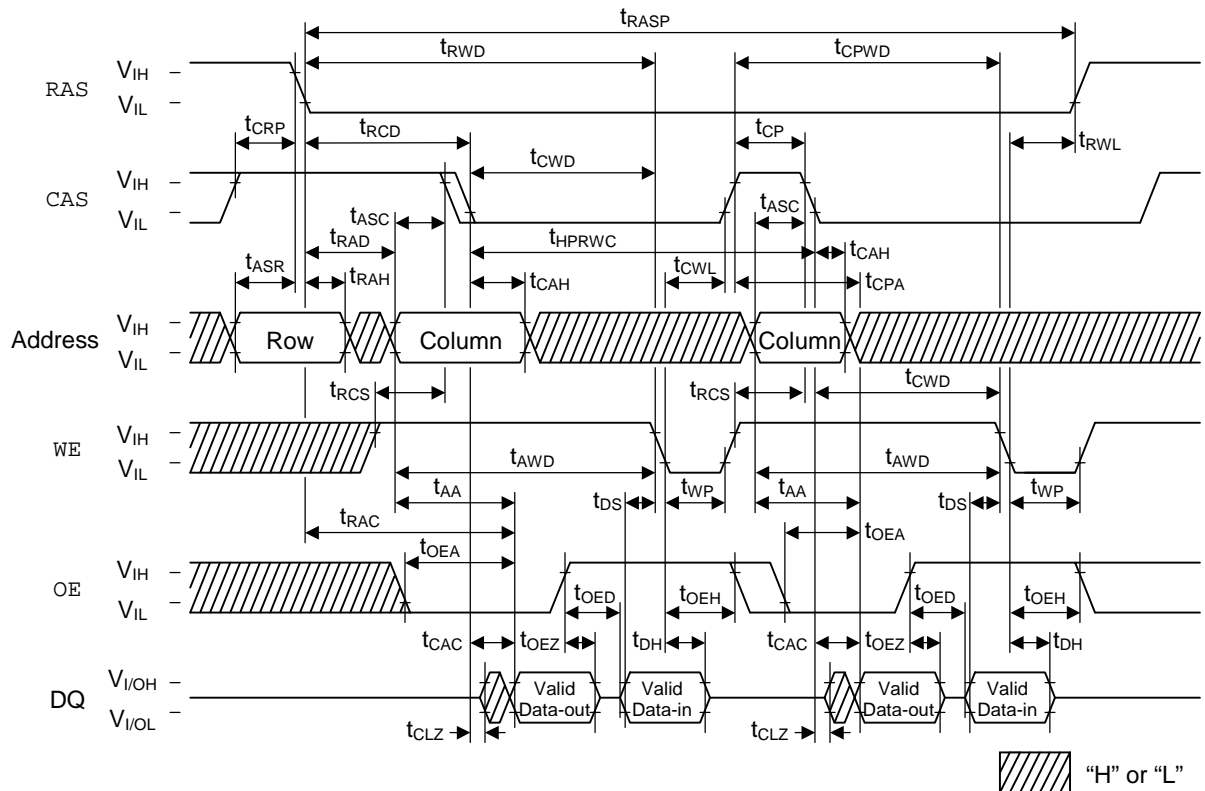
Fast Page Mode Read Cycle (Part-2)



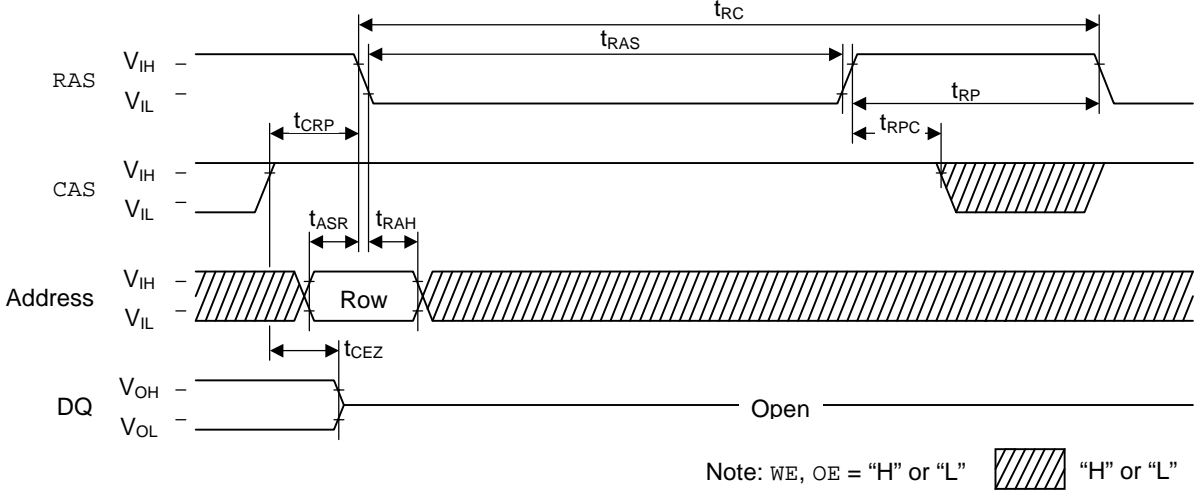
Fast Page Mode Write Cycle (Early Write)



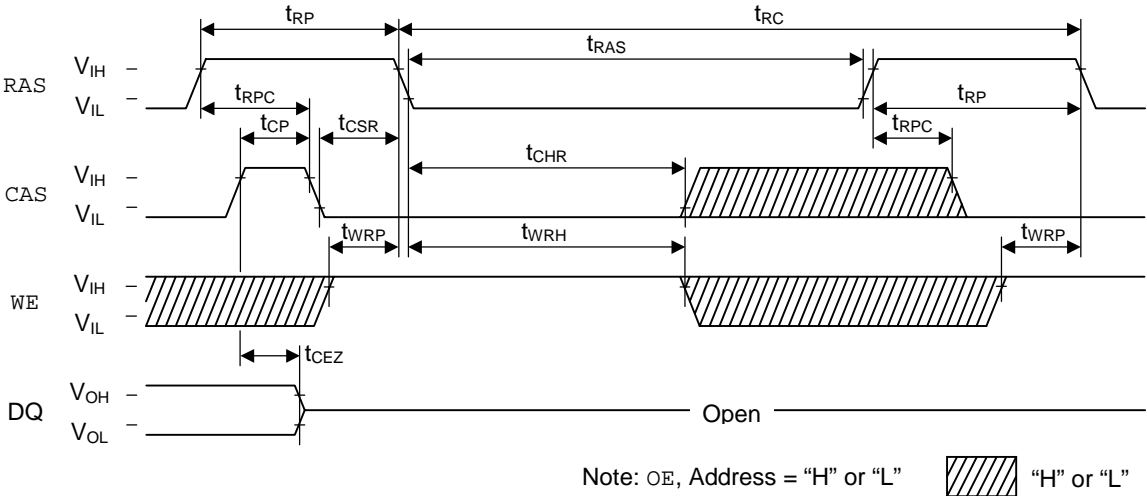
Fast Page Mode Read Modify Write Cycle



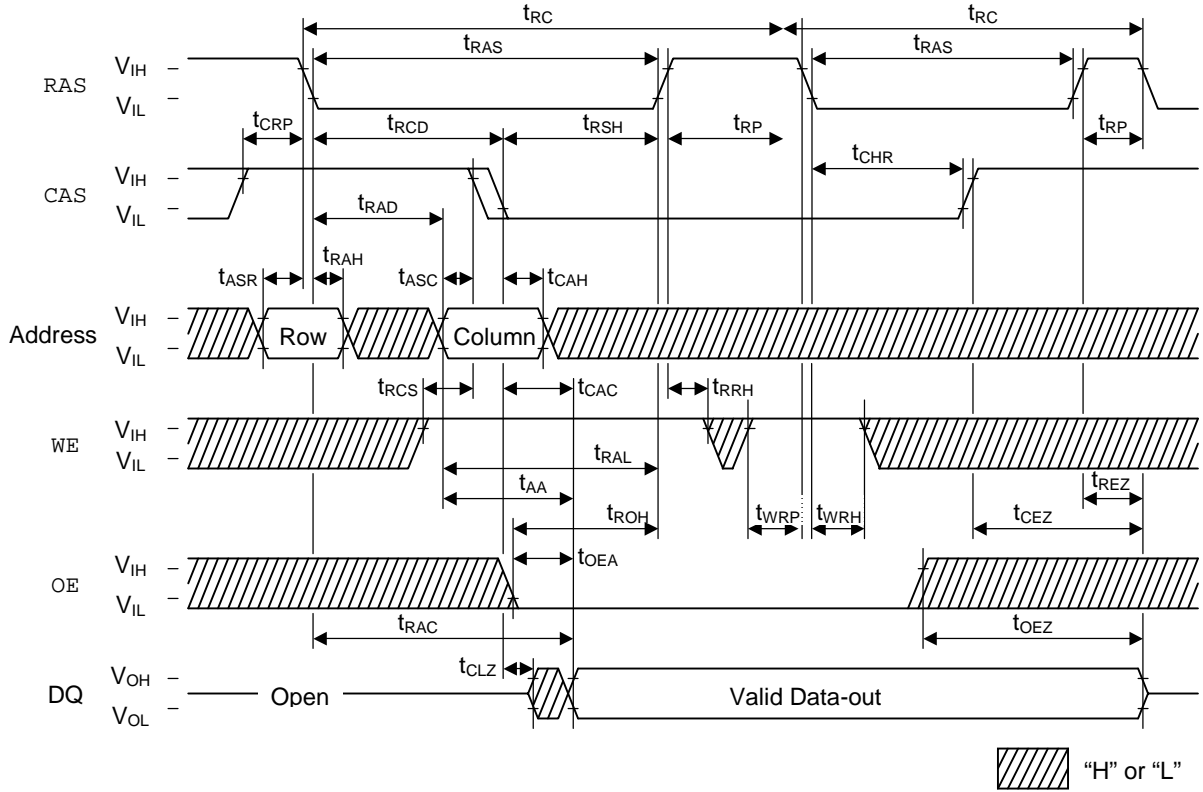
RAS-only Refresh Cycle



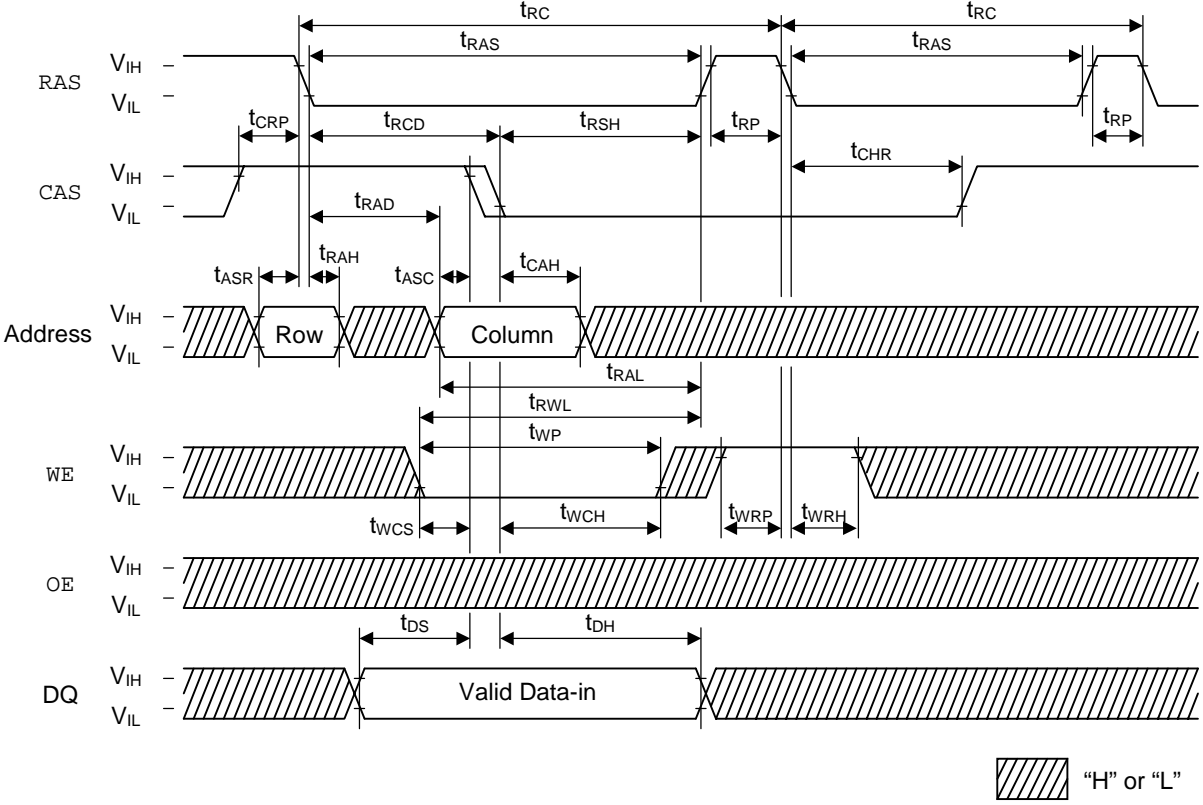
CAS before RAS Refresh Cycle



Hidden Refresh Read Cycle



Hidden Refresh Write Cycle



REVISION HISTORY

| Document No. | Date | Page | | Description |
|------------------|------------|------------------|-----------------|---------------------|
| | | Previous Edition | Current Edition | |
| FEDD51V65165E-01 | Jan., 2002 | – | – | Final edition 1 |
| FEDD51V65165E-02 | Aug., 2002 | 1, 2 | 1, 2 | Deleted SOJ package |

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